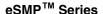


Vishay General Semiconductor

# **High-Current Density Surface Mount Schottky Rectifier**





DO-220AA (SMP)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	3.0 A			
V <sub>RRM</sub>	50 V, 60 V			
I <sub>FSM</sub>	45 A			
E <sub>AS</sub>	11.25 mJ			
V <sub>F</sub> at I <sub>F</sub> = 3.0 A	0.61 V			
T <sub>J</sub> max.	150 °C			

### **FEATURES**

· Very low profile - typical height of 1.0 mm



· Ideal for automated placement

Low forward voltage drop, low power losses



· High efficiency

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

## **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SS3P5	SS3P6	UNIT
Device marking code		35	36	
Maximum repetive peak reverse voltage	V <sub>RRM</sub>	50	60	V
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	3.0		Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	45		Α
Non-repetitive avalanche energy at $I_{AS}$ = 1.5 A, L = 10 mH, $T_{J}$ = 25 °C	E <sub>AS</sub>	11.25		mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/us
Operating junction and storage temperature range	T <sub>J,</sub> T <sub>STG</sub>	- 55 to + 150		°C

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage (1)	I <sub>F</sub> = 3 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.71 0.61	0.78 0.65	V
Maximum reverse current at rated V <sub>R</sub> <sup>(2)</sup>		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	2.0	100 10	μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	80		pF

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SS3P5	SS3P6	UNIT	
Typical thermal resistance <sup>(1)</sup>	$egin{array}{c} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	115 15 20		°C/W

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 15 x 15 mm copper pad areas.  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS3P6-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS3P6-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
SS3P6HE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
SS3P6HE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

#### Note:

(1) Automotive grade AEC Q101 qualified

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

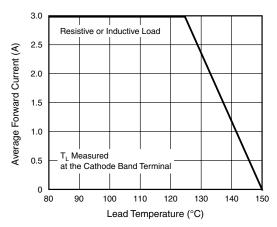


Figure 1. Forward Current Derating Curve

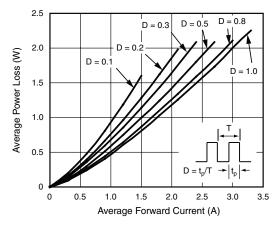


Figure 2. Forward Power Loss Characteristics

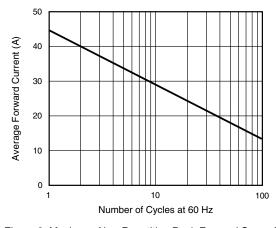


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

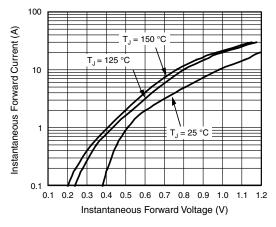


Figure 4. Typical Instantaneous Forward Characteristics



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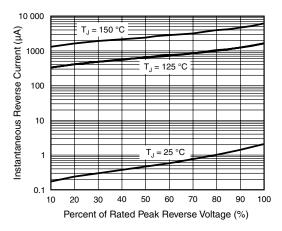


Figure 5. Typical Reverse Leakage Characteristics

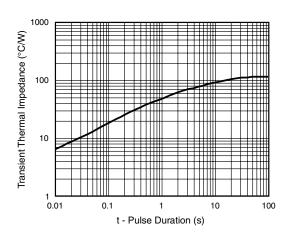


Figure 7. Typical Transient Thermal impedance

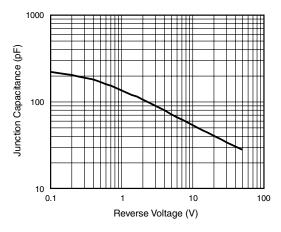


Figure 6. Typical Junction Capacitance

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-220AA (SMP) 0.012 (0.30) REF. Cathode band 0 0.086 (2.18) 0.053 (1.35) 0.036 (0.91) 0.074 (1.88) 0.041 (1.05) 0.024 (0.61) 0 0.142 (3.61) 0.103 (2.60) 0.032 (0.80) 0.126 (3.19) 0.087 (2.20) 0.016 (0.40) 0.158 (4.00) 0.146 (3.70) 0.025 0.030 (0.635) (0.762) 0.105 (2.67) 0.013 (0.35) 0.004 (0.10) 0.045 (1.15) 0.033 (0.85) 0.100 (2.54) 0.012 (0.30) 0.018 (0.45) 0.000 (0.00) 0.006 (0.15)



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